

1. General description

Planar passivated Silicon Controlled Rectifier with sensitive gate in a SOT54 (TO-92) plastic package. This SCR is designed to be interfaced directly to microcontrollers, logic ICs and other low power gate trigger circuits.

2. Features and benefits

- Enhanced voltage capability
- · Planar passivated for voltage ruggedness and reliability
- Sensitive gate
- · Direct triggering from low power drivers and logic ICs
- A-G-K reverse pin-out

3. Applications

General purpose switching and phase control

4. Quick reference data

Table 1. Qui	ck reference data					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{RRM}	repetitive peak reverse voltage		-	-	600	V
I _{T(AV)}	average on-state current	half sine wave; T _{lead} ≤ 83 °C; <u>Fig. 1</u>	-	-	0.5	A
I _{T(RMS)}	RMS on-state current	half sine wave; T _{lead} ≤ 83 °C; <u>Fig. 2;</u> <u>Fig. 3</u>	-	-	0.8	A
I _{TSM}	non-repetitive peak on- state current	half sine wave; T _{j(init)} = 25 °C; t _p = 10 ms; <u>Fig. 4; Fig. 5</u>	-	-	8	A
		half sine wave; T _{j(init)} = 25 °C; t _p = 8.3 ms	-	-	9	A
Tj	junction temperature		-	-	125	°C
Static chara	acteristics					
I _{GT}	gate trigger current	V _D = 12 V; I _T = 10 mA; T _j = 25 °C; <u>Fig. 7</u>	-	50	200	μA
Dynamic ch	naracteristics					
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 402 V; T _j = 125 °C; R _{GK} = 1 kΩ; (V_{DM} = 67% of V_{DRM}); exponential waveform; Fig. 12	500	800	-	V/µs

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
		V_{DM} = 402 V; T _j = 125 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit; Fig. 12	-	2	-	V/µs

5. Pinning information

Table 2. F	Pinning inf	ormation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	К	cathode		A + D+ K
2	G	gate		G sym037
3	A	anode	TO-92 (SOT54)	Synos

6. Ordering information

Table 3. Ordering information

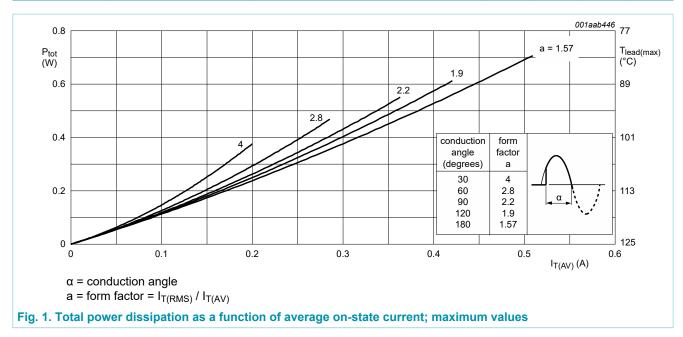
Type number	Package					
	Name	Description	Version			
BT149G	TO-92	plastic single-ended leaded (through hole) package; 3 leads	SOT54			

7. Limiting values

Table 4. Limiting values

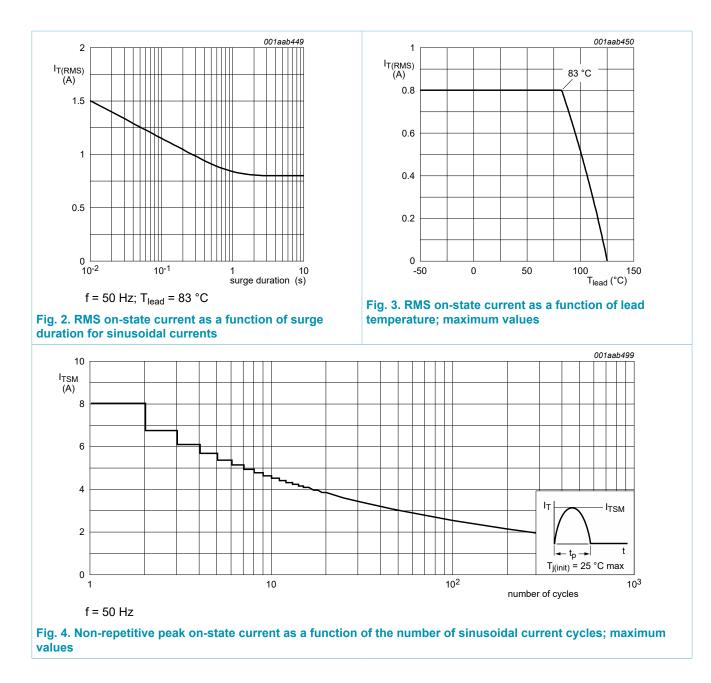
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DRM}	repetitive peak off-state voltage		-	600	V
V _{RRM}	repetitive peak reverse voltage		-	600	V
I _{T(AV)}	average on-state current	half sine wave; T _{lead} ≤ 83 °C; <u>Fig. 1</u>	-	0.5	А
I _{T(RMS)}	RMS on-state current	half sine wave; T _{lead} ≤ 83 °C; <u>Fig. 2</u> ; <u>Fig. 3</u>	-	0.8	А
I _{TSM}	non-repetitive peak on- state current	half sine wave; $T_{j(init)} = 25 \text{ °C}$; $t_p = 10 \text{ ms}$; Fig. 4; Fig. 5	-	8	A
		half sine wave; T _{j(init)} = 25 °C; t _p = 8.3 ms	-	9	А
l ² t	I ² t for fusing	t _p = 10 ms; SIN	-	0.32	A²s
dl _T /dt	rate of rise of on-state current	I _T = 2 A; I _G = 10 mA; dI _G /dt = 100 mA/μs	-	50	A/µs
I _{GM}	peak gate current		-	1	А
V _{RGM}	peak reverse gate voltage		-	5	V
P _{GM}	peak gate power		-	2	W
P _{G(AV)}	average gate power	over any 20 ms period	-	0.1	W
T _{stg}	storage temperature		-40	150	°C
Tj	junction temperature		-	125	°C



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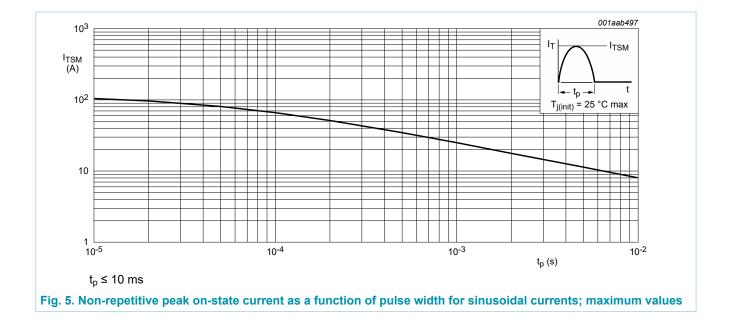


Product data sheet

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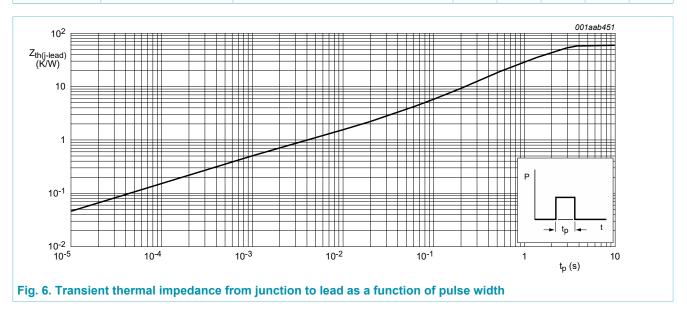
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8. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-lead)}	thermal resistance from junction to lead	<u>Fig. 6</u>	-	-	60	K/W
R _{th(j-a)}	thermal resistance from junction to ambient free air	printed circuit board mounted: lead length = 4 mm	-	150	-	K/W



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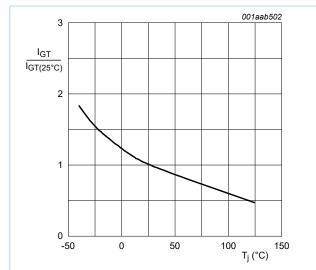
9. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics	· · · · · · · · · · · · · · · · · · ·				
I _{GT}	gate trigger current	V _D = 12 V; I _T = 10 mA; T _j = 25 °C; Fig. 7	-	50	200	μA
IL	latching current	V_D = 12 V; I _G = 0.5 mA; T _j = 25 °C; R _{GK(ext)} = 1 kΩ; Fig. 8	-	2	6	mA
I _H	holding current	V_D = 12 V; T _j = 25 °C; R _{GK(ext)} = 1 kΩ; Fig. 9	-	2	5	mA
V _T	on-state voltage	I _T = 1.2 A; T _j = 25 °C; <u>Fig. 10</u>	-	1.25	1.7	V
V _{GT}	gate trigger voltage	V _D = 12 V; I _T = 10 mA; T _j = 25 °C; <u>Fig. 11</u>	-	0.5	0.8	V
		V _D = 600 V; I _T = 10 mA; T _j = 125 °C; <u>Fig. 11</u>	0.2	0.3	-	V
I _D	off-state current	V_{D} = 600 V; $R_{GK(ext)}$ = 1 k Ω ; T_{j} = 125 °C	-	0.05	0.1	mA
I _R	reverse current	V_{R} = 600 V; T _j = 125 °C; R _{GK(ext)} = 1 kΩ	-	0.05	0.1	mA
Dynamic ch	naracteristics					
dV _D /dt	rate of rise of off-state voltage	$ V_{DM} = 402 \text{ V}; \text{T}_{\text{j}} = 125 ^{\circ}\text{C}; \text{R}_{\text{GK}} = 1 \text{k}\Omega; \\ (\text{V}_{\text{DM}} = 67\% \text{ of } \text{V}_{\text{DRM}}); \text{ exponential} \\ waveform; \underline{\text{Fig. 12}} $	500	800	-	V/µs
		V_{DM} = 402 V; T _j = 125 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit; Fig. 12	-	2	-	V/µs
t _{gt}	gate-controlled turn-on time	I_{TM} = 2 A; V _D = 600 V; I _G = 10 mA; dI _G / dt = 0.1 A/µs; T _j = 25 °C	-	2	-	μs
t _q	commutated turn-off time	V_{DM} = 402 V; T _j = 125 °C; I _{TM} = 1.6 A; V_R = 35 V; (dI _T /dt) _M = 30 A/µs; dV _D / dt = 2 V/µs; R _{GK(ext)} = 1 kΩ; (V _{DM} = 67% of V _{DRM})	-	100	-	μs

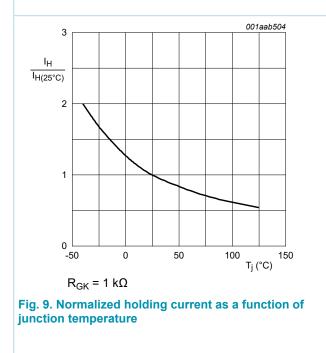
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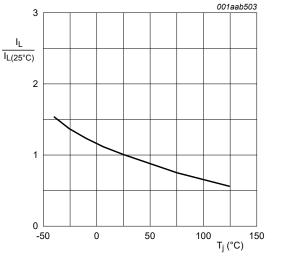
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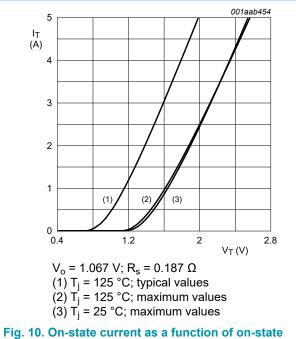








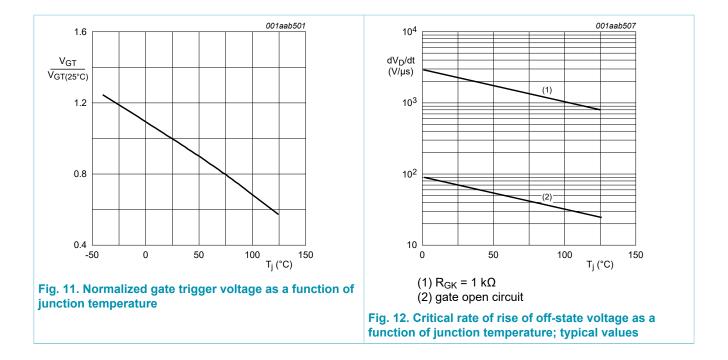




voltage

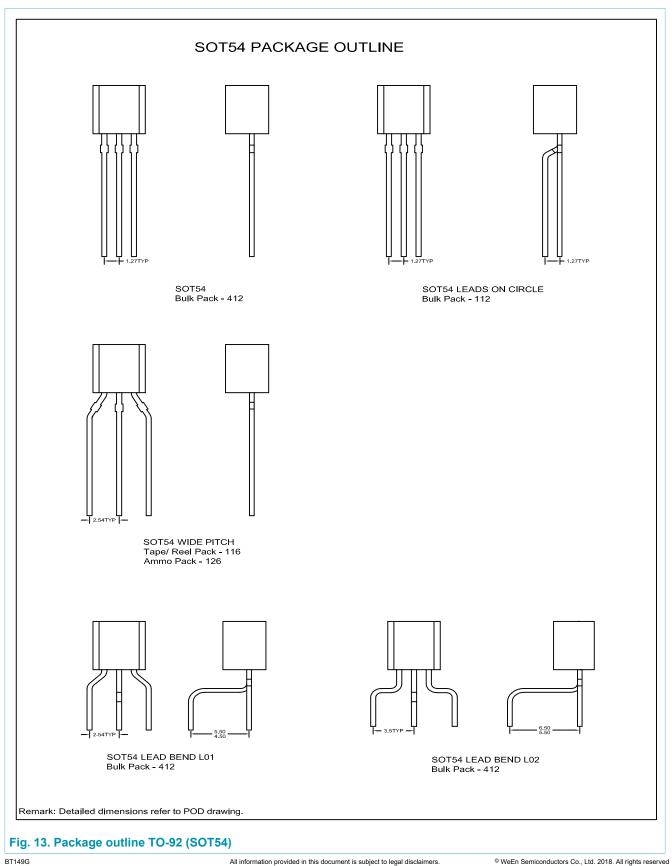
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10. Package outline



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11. Legal information

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Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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